**Product data sheet** 

## 1. General description

Silicon Carbide Schottky diode in a TO263 (D2PAK) plastic package, designed for high frequency switched-mode power supplies.

### 2. Features and benefits

- · Highly stable switching performance
- · High forward surge capability IFSM
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

## 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	-	650	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> $\leq$ 105 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4	-	-	16	Α
Static charact	eristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 16 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.5	1.7	V
		I <sub>F</sub> = 16 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	1.8	2.1	V

# **5. Pinning information**

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K-
2	K	cathode[1]	r	001aaa020
3	Α	anode		
mb	К	mounting base; connected to cathode	D2PAK (TO263N)	

<sup>[1]</sup> It is not possible to connect to pin 2 of the TO263 package.

## 6. Ordering information

**Table 3. Ordering information** 

Type number	Package						
	Name	Description	Version				
NXPSC16650B	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	TO263N				

## 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	650	V
$V_{RWM}$	crest working reverse voltage		-	650	V
$V_R$	reverse voltage	DC	-	650	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 105 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4	-	16	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 µs; square-wave pulse	-	32	Α
I <sub>FSM</sub>	non-repetitive peak	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse	-	96	Α
	forward current	t <sub>p</sub> = 10 μs; T <sub>j(init)</sub> = 25 °C; sine-wave pulse	-	770	Α
T <sub>stg</sub>	storage temperature		-55	175	°C
T <sub>j</sub>	junction temperature		-	175	°C

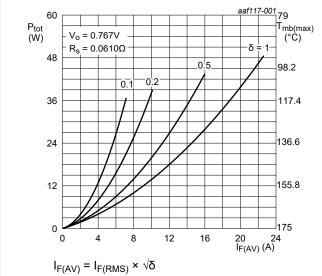


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

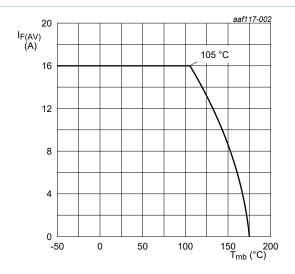


Fig. 2. Forward current as a function of mounting base temperature; maximum values

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#### Silicon Carbide Diode

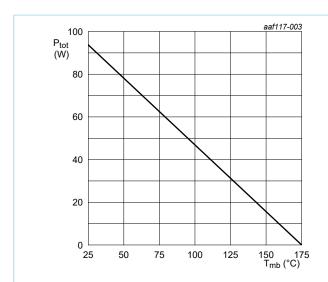


Fig. 3. Total power dissipation as a function of mounting base temperature

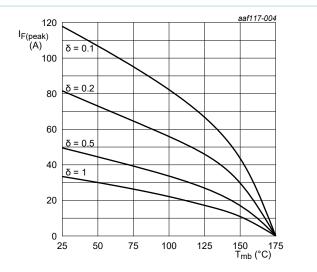


Fig. 4. Current derating as a function of mounting base temperature

### 8. Thermal characteristics

**Table 5. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	-	1.6	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W

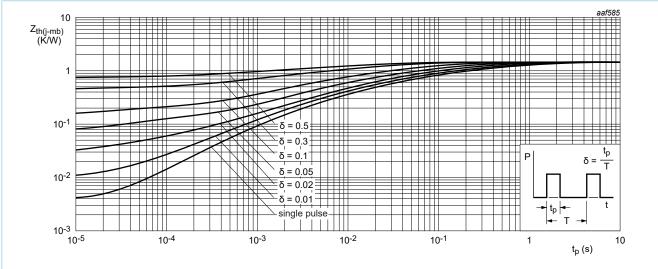
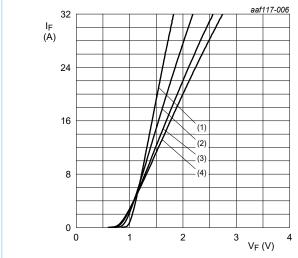


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

### 9. Characteristics

#### **Table 6. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static chara	Static characteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 16 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.5	1.7	V
		I <sub>F</sub> = 16 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.8	2.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C		-	-	100	μΑ
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 150 °C		-	-	400	μΑ
Dynamic ch	aracteristics						<u> </u>
Q <sub>r</sub>	recovered charge	$I_F = 16 \text{ A; } dI_F/dt = 500 \text{ A/}\mu\text{s;}$ $V_R = 400 \text{ V; } T_j = 25 \text{ °C; } Fig. 7$		-	26	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C		-	534	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C		-	75	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	73	-	pF



(1)  $T_j$  = 25 °C; typical values (2)  $T_j$  = 100 °C; typical values (3)  $T_j$  = 150 °C; typical values (4)  $T_j$  = 175 °C; typical values

Fig. 6. Forward current as a function of forward voltage; typical values

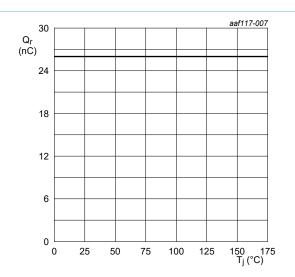
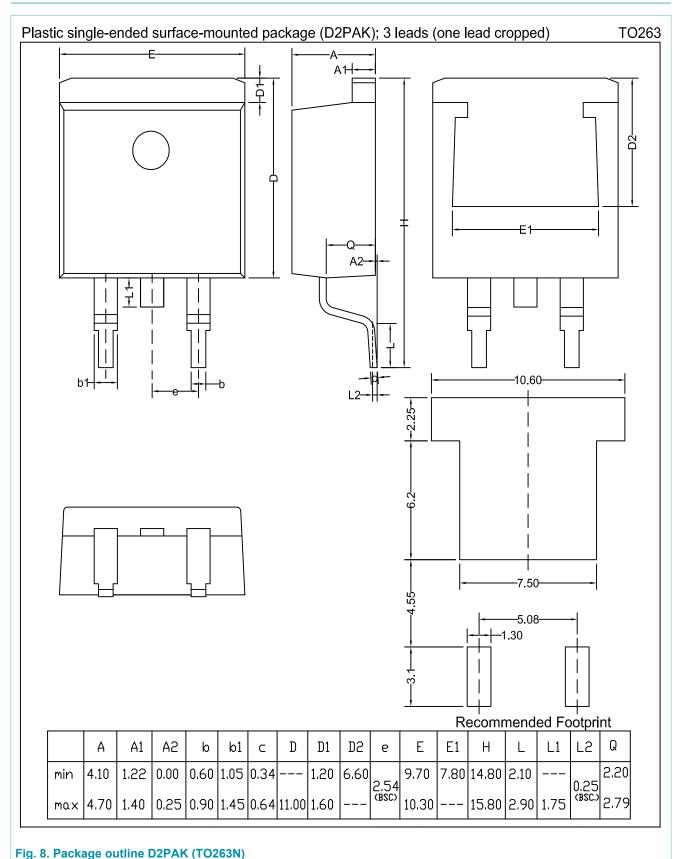


Fig. 7. Recovered charge as a function of junction temperature

## 10. Package outline



## 11. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## 12. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	. 1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Limiting values	. 3
8.	Thermal characteristics	. 5
9.	Characteristics	6
10.	Package outline	7
11.	Legal information	. 8

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